



**PDS4200H** 

### 4A HIGH VOLTAGE SCHOTTKY BARRIER RECTIFIER POWERDI<sup>®</sup>

## Features

- Lower Forward Voltage Drop than Ultrafast Rectifiers
- Very Low Leakage Current
- Soft Recovery Characteristics: Softness Factor  $(t_b/t_a) \geq 1$  (see figure 8)
- Highly Stable Oxide Passivated Junction
- High Forward Surge Current Capability
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: POWERDI5
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Weight: 0.095 grams (approximate)



### LEFT PIN o\_\_\_\_\_BOTTOMSIDE RIGHT PIN o\_\_\_\_\_►O HEAT SINK Note: Pins Left & Right must

be electrically connected at the printed circuit board.

### Ordering Information (Note 4)

Part Number	Case	Packaging
PDS4200H-13	POWERDI5	5000/Tape & Reel
PDS4200H-7	POWERDI5	1500/Tape & Reel

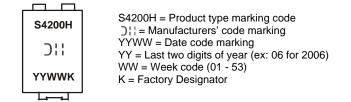
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and</li>

<1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

# **Marking Information**





## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.			
Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	200	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	141	V
Average Rectified Output Current (See also figure 5)	Io	4	А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load	I <sub>FSM</sub>	100	А

#### **Thermal Characteristics**

Characteristic	Symbol	Тур	Max	Unit
	Oymbol	тур		
Thermal Resistance Junction to Soldering Point	R <sub>0</sub> JS	—	3.0	°C/W
Thermal Resistance Junction to Ambient Air (Note 5)	R <sub>0JA</sub>	80	_	°C/W
Thermal Resistance Junction to Ambient Air (Note 6)	R <sub>0JA</sub>	65	_	°C/W
Thermal Resistance Junction to Ambient Air (Note 7)	$R_{ heta JA}$	45		°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +175		°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 8)	V <sub>(BR)R</sub>	200	_		V	I <sub>R</sub> = 5μA
Forward Voltage	VF		0.76  0.785 0.61 0.84 0.68	0.82 0.59 0.84 0.64 0.89 0.75	V	$I_{F} = 3A, T_{S} = +25^{\circ}C$ $I_{F} = 3A, T_{S} = +150^{\circ}C$ $I_{F} = 4A, T_{S} = +25^{\circ}C$ $I_{F} = 4A, T_{S} = +150^{\circ}C$ $I_{F} = 8A, T_{S} = +25^{\circ}C$ $I_{F} = 8A, T_{S} = +150^{\circ}C$
Reverse Leakage Current (Note 8)	I <sub>R</sub>		0.2 0.8	1 4	μA mA	$T_{S} = +25^{\circ}C, V_{R} = 200V$ $T_{S} = +150^{\circ}C, V_{R} = 200V$
Reverse Recovery Time	t <sub>rr</sub>			25	ns	$I_F = 0.5A, I_R = 1.0A$ $I_{RR} = 0.25A$ (see Figure 8)

Notes: 5. FR-4 PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com.

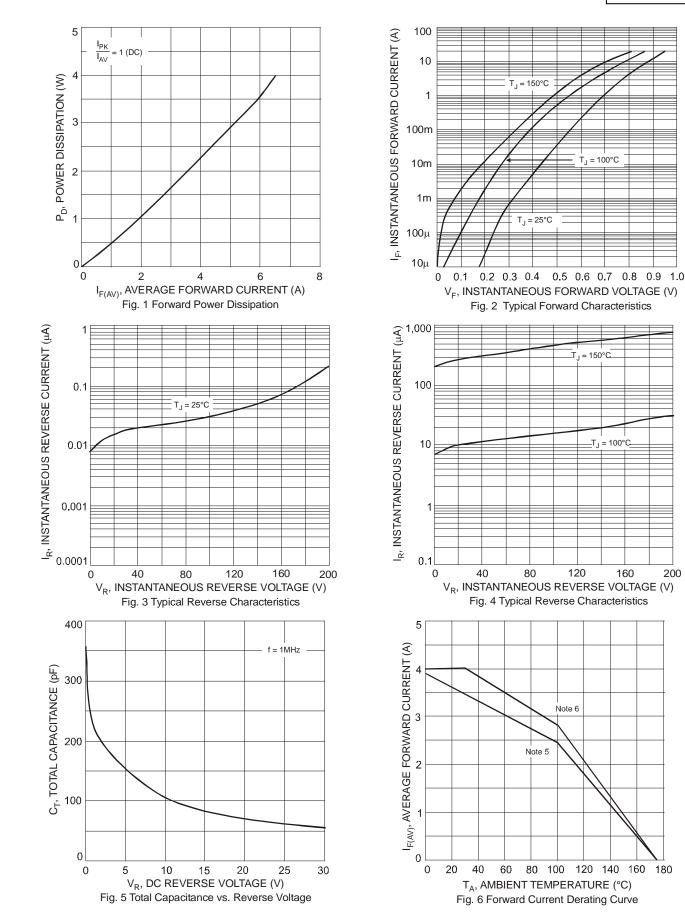
Polymide PCB, 2 oz. Copper, minimum recommended pad layout per http://www.diodes.com.
 Polymide PCB, 2 oz. Copper. Cathode pad dimensions 9.4mm x 7.2mm. Anode pad dimensions 2.7mm x 1.6mm.
 Short duration test pulse used to minimize self-heating effect.



 $T_{.1} = 100^{\circ}C$ 

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200



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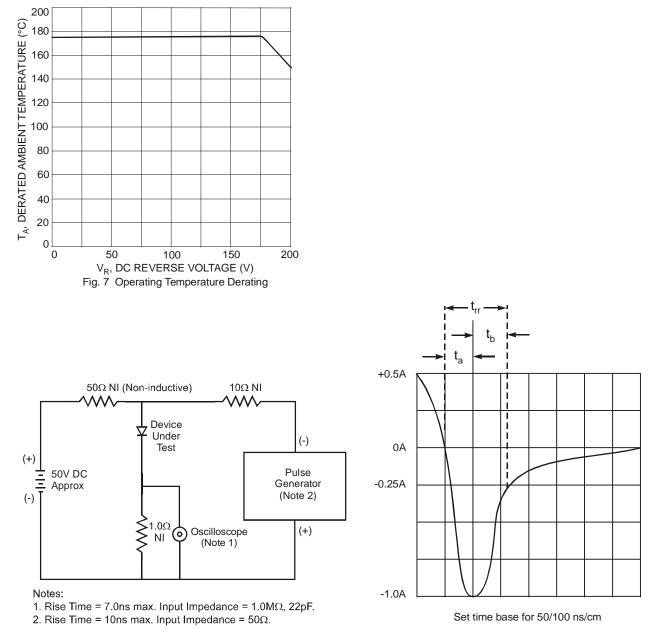
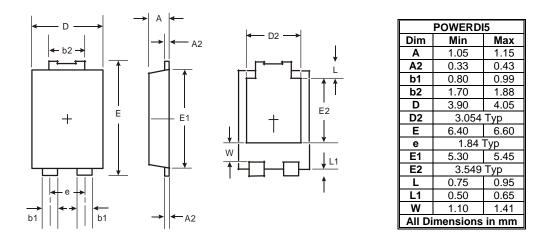


Fig. 8 Reverse Recovery Time Characteristic and Test Circuit



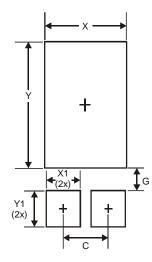
# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.840
G	0.852
Х	3.360
X1	1.390
Y	4.860
Y1	1.400



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